

ZXT4M322

MPPS™ Miniature Package Power Solutions

70V PNP LOW SATURATION TRANSISTOR

SUMMARY

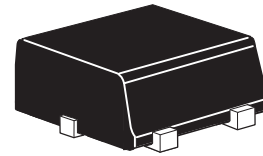
PNP— $V_{CE0} = -70V$; $R_{SAT} = 117m\Omega$; $I_C = -2.5A$

DESCRIPTION

Packaged in the new innovative 2mm x 2mm MLP (Micro Leaded Package) outline, this new 4th generation low saturation PNP transistor offers extremely low on state losses making it ideal for use in DC-DC circuits and various driving and power management functions.

Additionally users gain several other **key benefits**:

- Performance capability equivalent to much larger packages
- Improved circuit efficiency & power levels
- PCB area and device placement savings
- Lower Package Height (0.9mm nom)
- Reduced component count



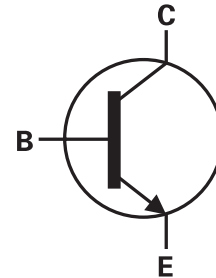
MLP322

FEATURES

- Low Equivalent On Resistance
- Extremely Low Saturation Voltage ($-220mV$ max @1A)
- h_{FE} specified up to 3A
- $I_C = 2.5A$ Continuous Collector Current
- 2mm x 2mm MLP

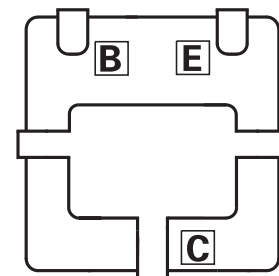
APPLICATIONS

- DC - DC Converters
- DC - DC Modules
- Power switches
- Motor control



ORDERING INFORMATION

DEVICE	REEL SIZE	TAPE WIDTH	QUANTITY PER REEL
ZXTD4M322TA	7"	8mm	3000
ZXTD4M322TC	13"	8mm	10000



Underside View

DEVICE MARKING

- S4

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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Collector-Base Voltage	V_{CB0}	-70	V
Collector-Emitter Voltage	V_{CEO}	-70	V
Emitter-Base Voltage	V_{EBO}	-7.5	V
Peak Pulse Current	I_{CM}	-3	A
Continuous Collector Current ^(a)	I_C	-2.5	A
Base Current	I_B	-1000	mA
Power Dissipation at $T_A=25^\circ\text{C}$ ^(a)	P_D	1.5	W
Linear Derating Factor		12	mW/ $^\circ\text{C}$
Power Dissipation at $T_A=25^\circ\text{C}$ ^(b)	P_D	2.45	W
Linear Derating Factor		19.6	mW/ $^\circ\text{C}$
Power Dissipation at $T_A=25^\circ\text{C}$ ^(d)	P_D	1	W
Linear Derating Factor		8	mW/ $^\circ\text{C}$
Power Dissipation at $T_A=25^\circ\text{C}$ ^(e)	P_D	3	W
Linear Derating Factor		24	mW/ $^\circ\text{C}$
Operating & Storage Temperature Range	$T_j:T_{stg}$	-55 to +150	$^\circ\text{C}$
Junction Temperature	T_j	150	$^\circ\text{C}$

THERMAL RESISTANCE

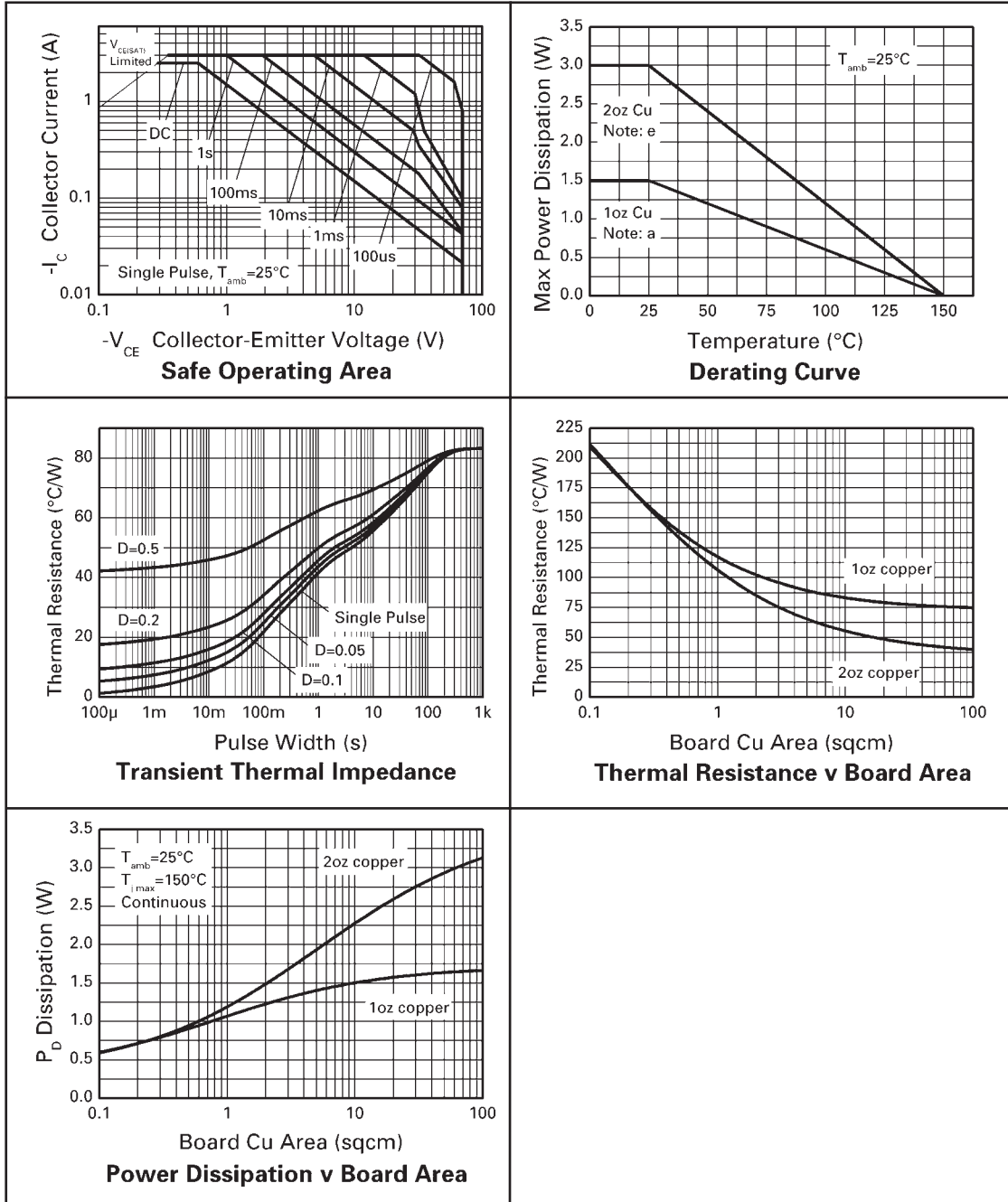
PARAMETER	SYMBOL	VALUE	UNIT
Junction to Ambient ^(a)	$R_{\theta JA}$	83	$^\circ\text{C}/\text{W}$
Junction to Ambient ^(b)	$R_{\theta JA}$	51	$^\circ\text{C}/\text{W}$
Junction to Ambient ^(d)	$R_{\theta JA}$	125	$^\circ\text{C}/\text{W}$
Junction to Ambient ^(e)	$R_{\theta JA}$	42	$^\circ\text{C}/\text{W}$

NOTES

- (a) For a single device surface mounted on 10 sq cm 1oz copper on FR4 PCB, in still air conditions **with all exposed pads attached**.
- (b) For a single device surface mounted on 10 sq cm 1oz copper on FR4 PCB, in still air conditions measured at $t \leq 5$ secs **with all exposed pads attached**.
- (c) Repetitive rating - pulse width limited by max junction temperature. Refer to Transient Thermal Impedance graph.
- (d) For a single device surface mounted on 10 sq cm 1oz copper FR4 PCB, in still air conditions **with minimal lead connections only**.
- (e) For a single device surface mounted on 65 sq cm 2oz copper FR4 PCB, in still air conditions **with all exposed pads attached**.
- (f) The minimum copper dimensions required for mounting are no smaller than the exposed metal pads on the base of the device, as shown in the package dimensions data. The thermal resistance for a device mounted on 1.5mm thick FR4 board using minimum copper of 1oz weight and 1mm wide tracks is $R_{th} = 300^\circ\text{C}/\text{W}$ giving a power rating of $P_{tot} = 420\text{mW}$

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TYPICAL CHARACTERISTICS



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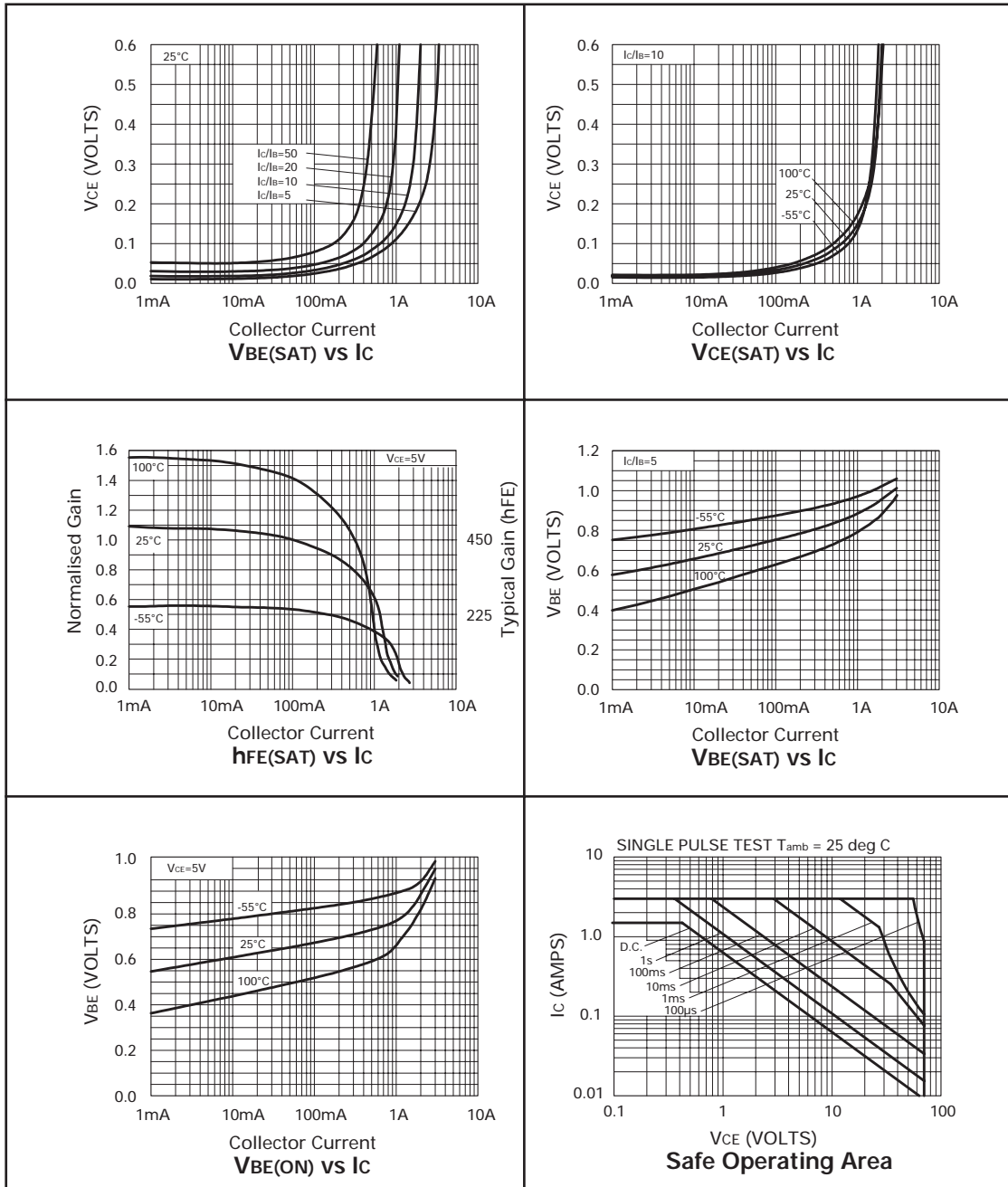
ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-70	-150		V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-70	-125		V	$I_C = -10\text{mA}^*$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-7.5	-8.5		V	$I_E = -100\mu\text{A}$
Collector Cut-Off Current	I_{CBO}			-25	nA	$V_{CB} = -55\text{V}$
Emitter Cut-Off Current	I_{EBO}			-25	nA	$V_{EB} = -6\text{V}$
Collector Emitter Cut-Off Current	I_{CES}			-25	nA	$V_{CE} = -55\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		-35 -135 -140 -175	-50 -200 -220 -260	mV	$I_C = -0.1\text{A}, I_B = -10\text{mA}^*$ $I_C = -0.5\text{A}, I_B = -20\text{mA}^*$ $I_C = -1\text{A}, I_B = -100\text{mA}^*$ $I_C = -1.5\text{A}, I_B = -200\text{mA}^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		-0.94	-1.05	V	$I_C = -1.5\text{A}, I_B = -200\text{mA}^*$
Base-Emitter Turn-On Voltage	$V_{BE(on)}$		-0.78	-1.00	V	$I_C = -1.5\text{A}, V_{CE} = -5\text{V}^*$
Static Forward Current Transfer Ratio	h_{FE}	300 300 175 40	470 450 275 60 10			$I_C = -10\text{mA}, V_{CE} = -5\text{V}^*$ $I_C = -100\text{mA}, V_{CE} = -5\text{V}^*$ $I_C = -1\text{A}, V_{CE} = -5\text{V}^*$ $I_C = -1.5\text{A}, V_{CE} = -5\text{V}^*$ $I_C = -3\text{A}, V_{CE} = -5\text{V}^*$
Transition Frequency	f_T	150	180		MHz	$I_C = -50\text{mA}, V_{CE} = -10\text{V}$ $f = 100\text{MHz}$
Output Capacitance	C_{obo}		14	20	pF	$V_{CB} = -10\text{A}, f = 1\text{MHz}$
Turn-On Time	$t_{(on)}$		40		ns	$V_{CC} = -50\text{V}, I_C = -1\text{A}$
Turn-Off Time	$t_{(off)}$		700		ns	$I_{B1} = I_{B2} = -50\text{mA}$

*Measured under pulsed conditions. Pulse width=300 μs . Duty cycle $\leq 2\%$

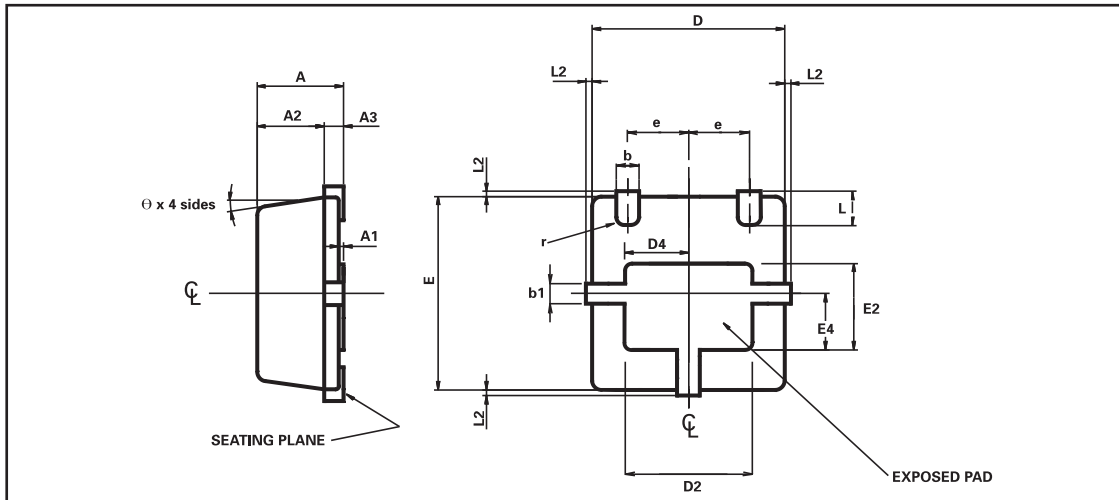
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TYPICAL CHARACTERISTICS



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PACKAGE OUTLINE



Controlling dimensions are in millimetres. Approximate conversions are given in inches

PACKAGE DIMENSIONS

DIM	Millimetres		Inches		DIM	Millimetres		Inches	
	Min	Max	Min	Max		Min	Max	Min	Max
A	0.80	1.00	0.0315	0.0393	e	0.65 REF		0.0255 REF	
A1	0.00	0.05	0.00	0.002	E	2.00 BSC		0.0787	
A2	0.65	0.75	0.0255	0.0295	E2	0.79	0.99	0.031	0.039
A3	0.15	0.25	0.0059	0.0098	E4	0.48	0.68	0.0188	0.0267
b	0.18	0.28	0.0070	0.0110	L	0.20	0.45	0.0078	0.0177
b1	0.17	0.30	0.0066	0.0118	L2	0.125 MAX.		0.005 REF	
D	2.00 BSC		0.0787 BSC		r	0.075 BSC		0.0029 BSC	
D2	1.22	1.42	0.0480	0.0559	θ	0°	12°	0°	12°
D4	0.56	0.76	0.0220	0.0299					

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ISSUE 1 - JUNE 2003

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